P/N:DBLNA100180066A

QOTANA TECHNOLOGIES Wide Band Low Noise Amplifier 180MHz~660MHz

Features

- Gain: 26dB Typical
- Noise Figure: 0.6dB Typical
- P1dB Output Power: +23dBm
- Supply Voltage: +5V @ 115mA



RoHS COMPLIANT

ESD

Typical Applications

- Wireless Infrastructure
- Military & Aerospace
- Fiber Optics

RF Microwave & VSAT
Test Instrument

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	180		400	400		660	MHz
Gain	25	27		23	24		dB
Gain Flatness		±0.6	±1.0		±1.0	±1.5	dB
Gain Variation Over Temperature(-45 ~ +85)		±0.6	±1.0		±0.8	±1.0	dB
Noise Figure		0.6	0.8		0.6	0.8	dB
Input VSWR		1.6			1.5		: 1
Output VSWR		1.8			1.7		: 1
Output Power for 1 dB Compression (P1dB)	20	23		20	23		dBm
Saturated Output Power (Psat)		25			25		dBm
Output Third Order Intercept (IP3)		37			36		dBm
Supply Current (Vcc=+5V)		115	150		115	150	mA
Isolation S12		-32			-31		dB

Weight	0.71 ounces	Impedance	50ohms
Input / Output Connectors	SMA-Female	Material	Aluminum
Finishing	Standard: Gold 40 micron; Nickel 220 micron thickness	Package Sealing	Epoxy Sealing (Standard)
	Option: Gold 80 micron; Nickel 180 micron thickness		Hermetically Seal (Option with extra charge)

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Absolute Maximum Ratings

Operating Voltage	+6V
RF Input Power(RFIN)	+18dBm

Biasing Up Procedure

Step 1	Connect Ground Pin
Step 2	Connect input and output
Step 3	Connect +5V biasing

Power OFF Procedure

Step 1	Turn off +5V biasing
Step 2	Remove RF connection
Step 3	Remove Ground

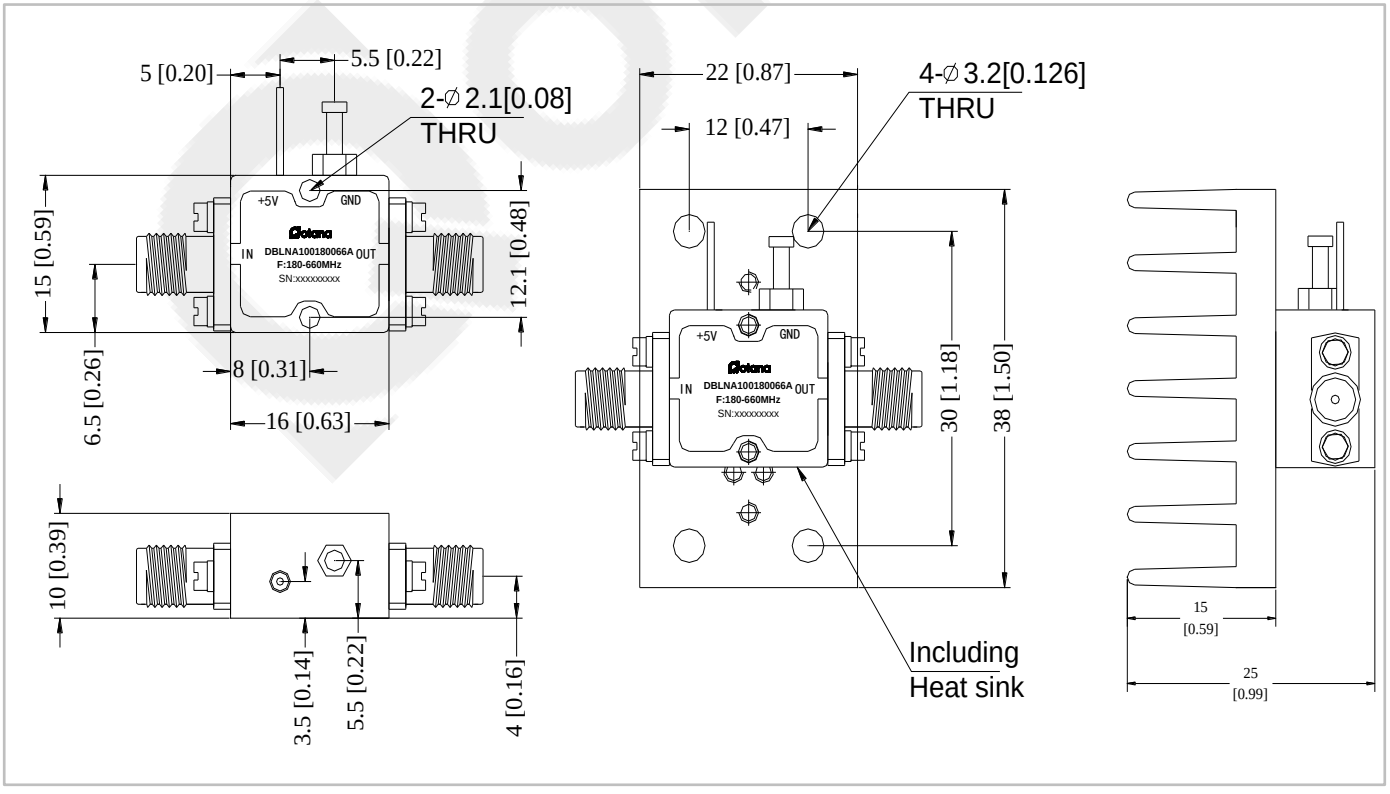
Environmental Specifications

Operational Temperature	-45ºC~+85ºC
Storage Temperature	-55ºC~+125ºC
Altitude	30,000 ft. (Epoxy Sealed Controlled environment)
	60,000 ft. 1.0psi min (Hermetically Sealed Un-controlled environment) (Optional)
Vibration	25g RMS (15 degrees 2KHz) endurance, 1 hour per axis
Humidity	100% RH at 35c, 95%RH at 40ºc
Shock	20G for 11msec half sine wave,3 axis both directions

Outline Drawing:

All Dimensions in mm (inches)

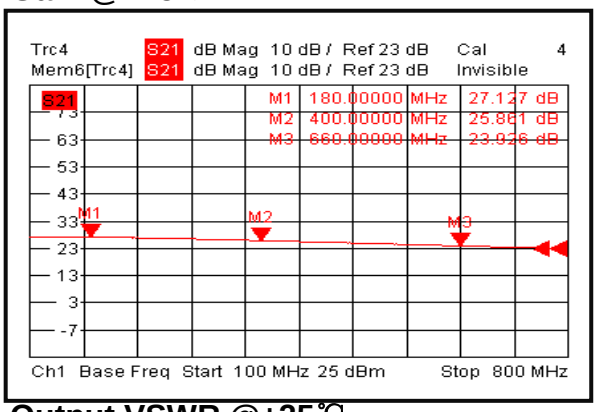
Heat Sink required during operation(Sold Seperately)



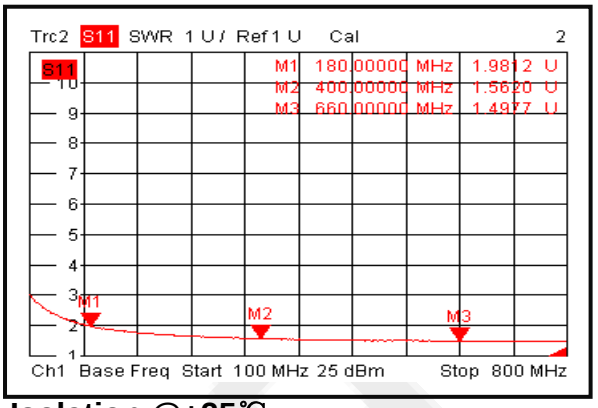
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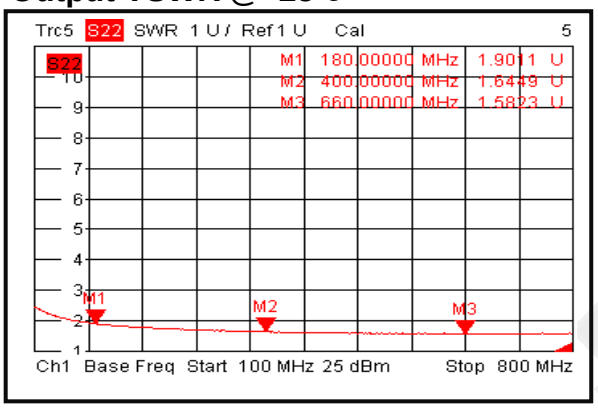
Gain @+25℃



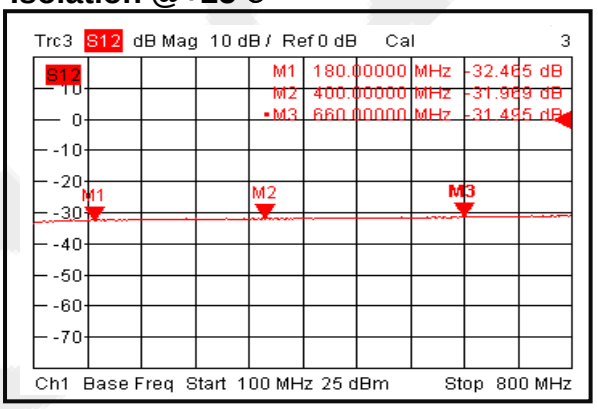
Input VSWR @+25℃



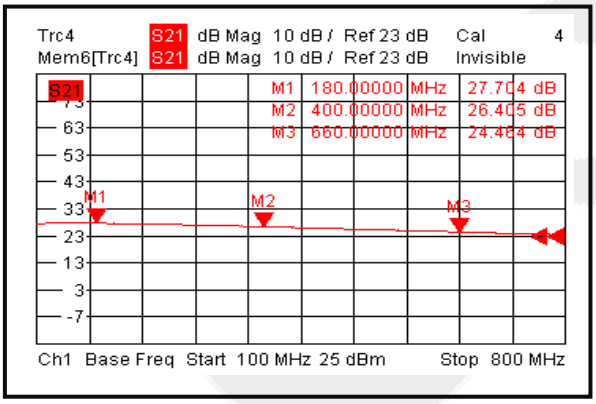
Output VSWR @+25℃



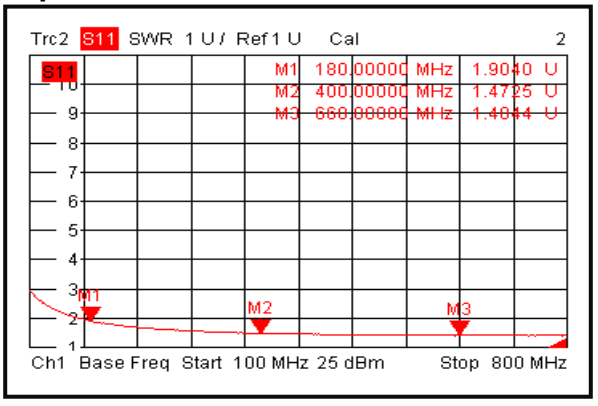
Isolation @+25℃



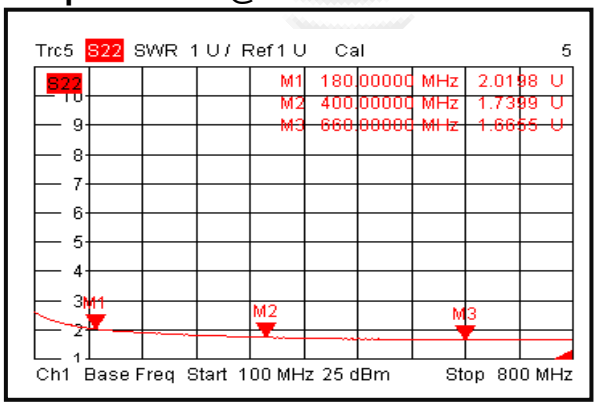
Gain @-45℃



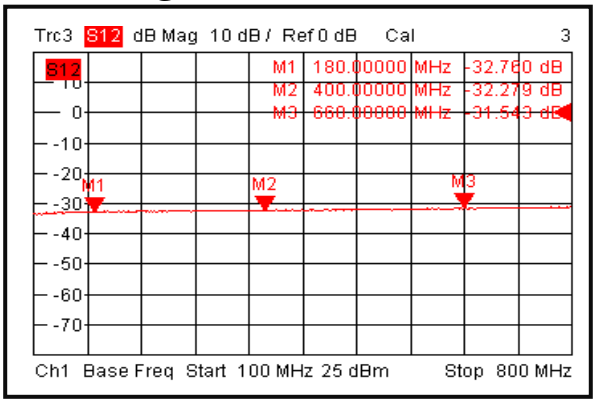
Input VSWR @-45℃



Output VSWR @-45℃



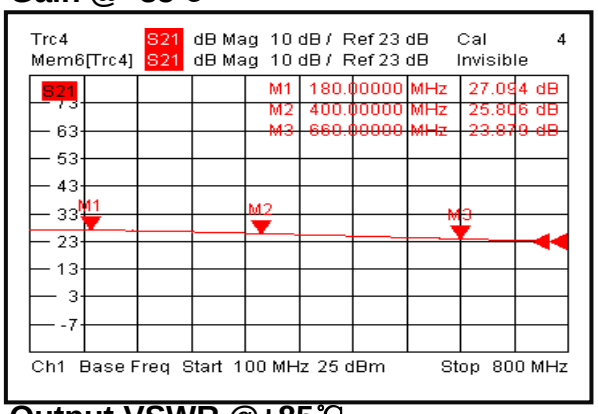
Isolation @-45℃



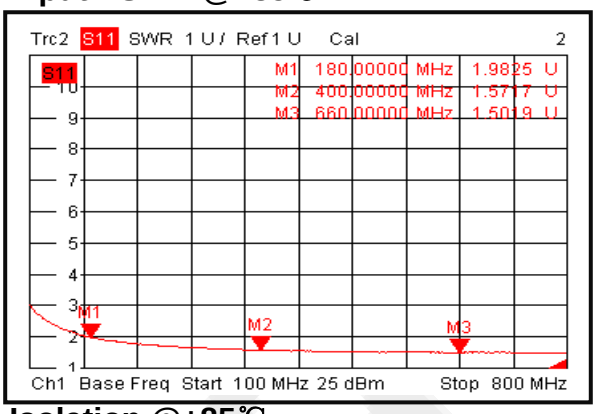
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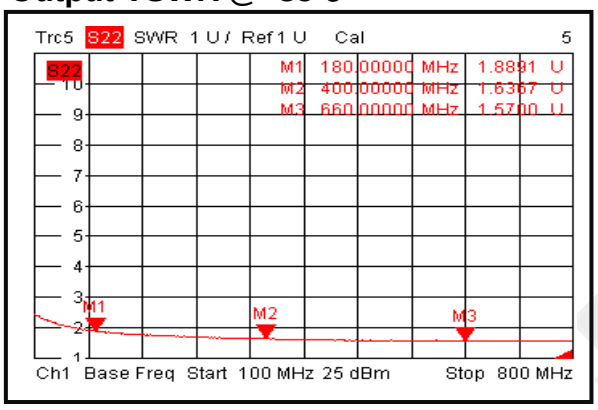
Gain @+85℃



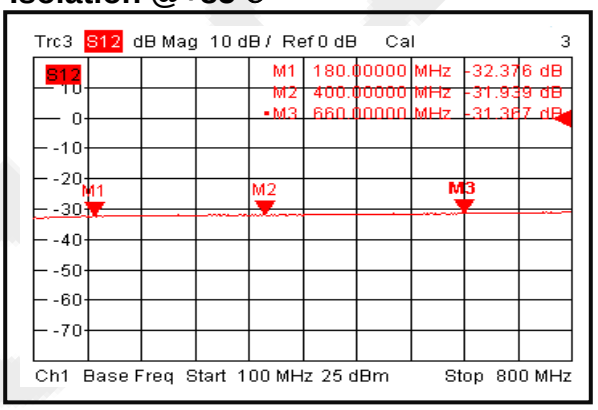
Input VSWR @+85℃



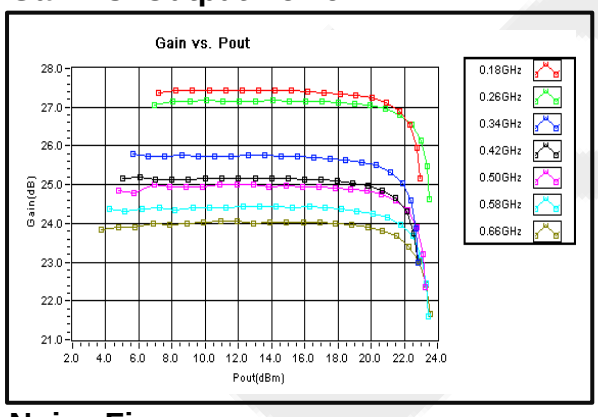
Output VSWR @+85℃



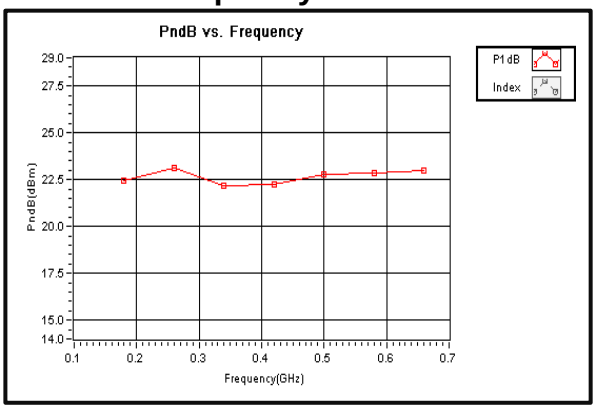
Isolation @+85℃



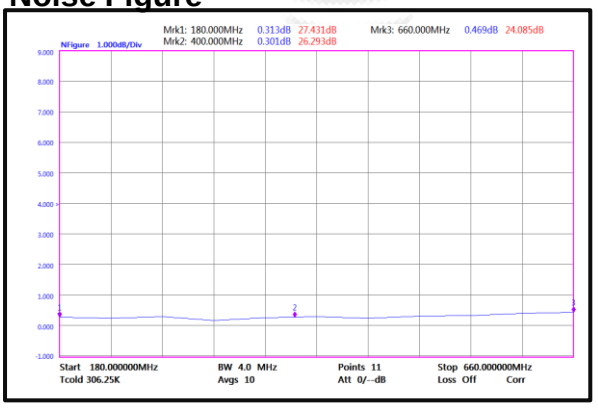
Gain vs. Output Power



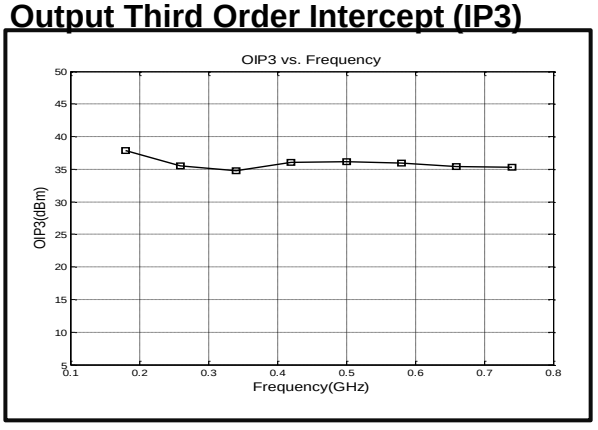
P1dB vs. Frequency



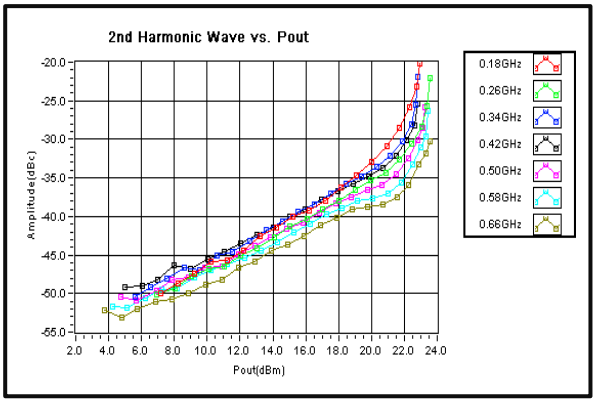
Noise Figure



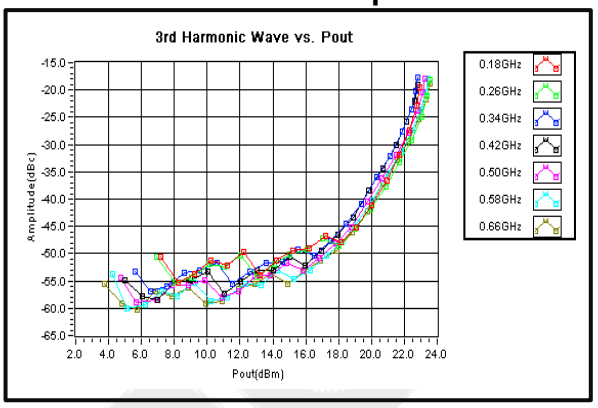
Output Third Order Intercept (IP3)



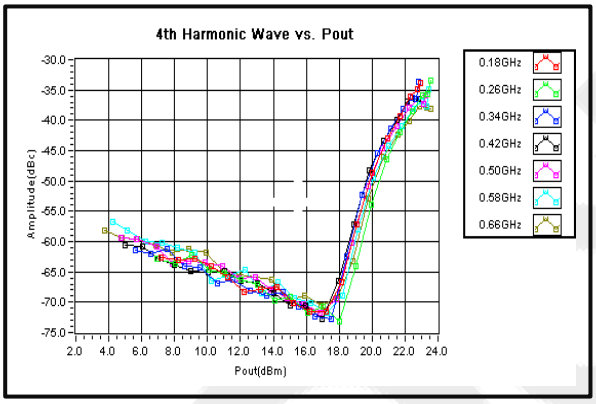
2nd Harmonic Wave Output Power



3rd Harmonic Wave Output Power



4th Harmonic Wave Output Power



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